

Data sheet acquired from Harris Semiconductor SCHS045

CMOS Multifunction Expandable 8-Input Gate

High-Voltage Types (20-Volt Rating)

FOD4048B is an 8-input gate having four control inputs. Three binary control inputs — Ka, Kb, and Kc — provide the implementation of eight different logic functions. These functions are OR, NOR, AND, NAND, OR/AND, OR/NAND, AND/OR and AND/NOR.

A fourth control input, Kd, provides the user with a 3-state output. When control input Kd is high, the output is either a logic 1 or a logic 0 depending on the inner states. When control input Kd is low, the output is an open circuit. This feature enables the user to connect this device to a common bus line.

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY-VOLTAGE RANGE, (VDD)

POWER DISSIPATION PER PACKAGE (PD):

DEVICE DISSIPATION PER OUTPUT TRANSISTOR

LEAD TEMPERATURE (DURING SOLDERING):

In addition to the eight input lines, an EXPAND input is provided that permits the user to increase the number of inputs into a CD4048B (see Fig. 2). For example, two CD4048B's can be cascaded to provide a 16-input multifunction gate. When the EXPAND input is not used, it should be connected to VSS.

The CD4048B-series types are supplied in 16-lead hermetic dual-in-line ceramic packages (D and F suffixes), 16-lead dual-in-line plastic packages (E suffix), and in chip form (H suffix).

Features:

- Three-state output
- Many logic functions available in one package
- Standardized, symmetrical output characteristics

CD4048B Types

- 100% tested for quiescent current at 20 V
- Maximum input current of 1 µA at 18 V (full package-temperature range), 100 nA at 18 V and 25°C
- Noise margin (full package-temperature range) = 1 V at V_{DD}=5 V, 2 V at V_{DD} = 10 V, 2.5 V at V_{DD}=15 V
- 5-V, 10-V, and 15-V parametric ratings
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"

 Voltages referenced to V_{SS} Terminal)
 -0.5V to +20V

 INPUT VOLTAGE RANGE, ALL INPUTS
 -0.5V to V_{DD} +0.5V

DC INPUT CURRENT, ANY ONE INPUT±10mA

OPERATING-TEMPERATURE RANGE (TA).....-55°C to +125°C

STORAGE TEMPERATURE RANGE (T_{stg}).....-65°C to +150°C

At distance 1/16 ± 1/32 inch (1.59 ± 0.79mm) from case for 10s max

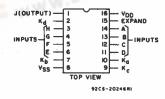
RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	LIM	UNITS	
CHARACTERISTIC	MIN.	MIN. MAX.	
Supply-Voltage Range (For T _A = Full Package Temperature Range)	3	18	V

Applications:

- Selection of up to 8 logic functions
- Digital control of logic
- General-purpose gating logic
 - Decoding
 - Encoding



TERMINAL ASSIGNMENT

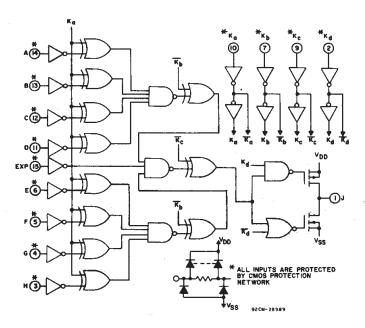
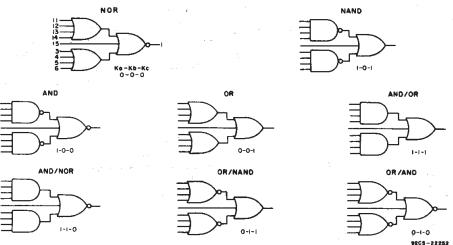


Fig. 2 - Logic diagram.



 ${\it Fig.~3-Actual-circuit~logic~configurations.}$

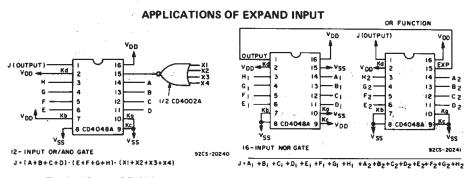


Fig. 4 - 12-input OR/AND gate.

Fig. 5 - 16-input NOR gate.

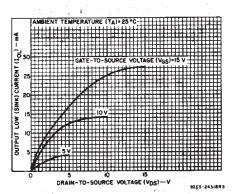


Fig. 6 — Typical output low (sink) current characteristics.

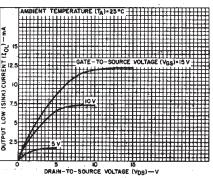


Fig. 7 — Minimum output low (sink) current characteristics.

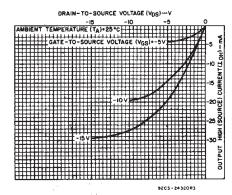


Fig. 8 — Typical output high (source) current characteristics.

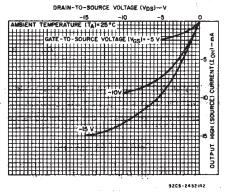


Fig. 9 — Minimum output high (source) current characteristics.

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STATIC ELECTRICAL CHARACTERISTICS

	,										
CHARACTER-	CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)							
ISTIC	Vo	VIN	VDD	L					+25		UNITS
	(V)	(V)	(V)	55	-40	+85	+125	Min.	Тур.	Max.]
Quiescent Device	_	0,5	5	0.25	0.25	7.5	7.5	_	0.01	0.25	
Current,	_	0,10	10	0.5	0.5	15	15	-	0.01	0.5	
IDD Max.		0,15	15	1	1	30	30	-	0.01	1	μΑ
		0,20	20	5	5	150	150	-	0.02	5	
Output Low	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1	٠	
(Sink) Current	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6	_	1
IOL Min.	1.5	0,15	15	4.2	4	2.8	2.4	3.4	6.8	-	1
Output High	4.6	0,5	5	-0.64	-0.61	-0.42	-0.36	-0.51	1	. –	mA
(Source)	2.5	0,5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	-	1
Current, IOH Min.	9.5	0,10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	-	
	13.5	0,15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8	_	
Output Voltage:	_	0,5	5		0	.05		_	0	0.05	
Low-Level, VOL Max.		0,10	10	0.05				_	0	0.05	v
VOE Max.	_	0,15	15	0.05			÷	0	0.05		
Output Voltage:	-	0,5	5	4.95			4.95	5	_		
High-Level,		0,10	10		9.95			9.95	10		
VOH Min.		0,15	15	14.95				14.95	15	-	
Input Low	0.5,4.5	_	5		1.5				_	1.5	
Voltage,	1,9		10	3				_	_	3	
VIL Max.	1.5,13.5	_	15		4					4	
Input High Voltage,	0.5,4.5	_	5		3.5			3.5		_	٧
	1,9	_	10		7 7 – –				_		
VIH Min.	1.5,13.5	-	15	11				11		_	
Input Current IJN Max.		0,18	18	±0.1	±0.1	±1	±1	_	±10 ⁻⁵	±0.1	μΑ
3-State Output Current, IOUT	0,18	0,18	18	±0.4	±0.4	±12	±12	_	±10 ⁻⁴	±0.4	μΑ

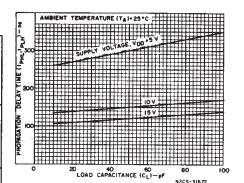


Fig. 10 -- Typical propagation delay time (logic inputs to output) as a function of load capacitance.

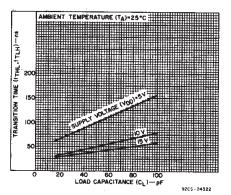


Fig. 11 - Typical transition time vs. load capacitance.

IMPLEMENTATION OF EXPAND INPUT FOR 9 OR MORE INPUTS

OUTPUT FUNCTION	FUNCTION NEEDED AT EXPAND INPUT	OUTPUT BOOLEAN EXPRESSION		
NOR	OR	J=(A+B+C+D+E+F+G+H)+(EXP)		
OR	OR	J=(A+B+C+D+E+F+G+H)+(EXP)		
AND	NAND	J=(ABCDEFGH)·(EXP)		
NAND	NAND	J=(ABCDEFGH)·(EXP)		
OR/AND	NOR	J=(A+B+C+D)-(E+F+G+H)-(EXP)		
OR/NAND	NOR	J=(A+B+C+D)·(E+F+G+H)·(EXP)		
AND/NOR	AND	J=(ABCD)+(EFGH)+(EXP)		
AND/OR	AND	J=(ABCD)+(EFGH)+(EXP)		

Note: (EXP) designates the EXPAND function (i.e., $x_1 + x_2 + \dots + x_N$).

NOTE: Refer to FUNCTION TRUTH TABLE for connection of unused inputs.

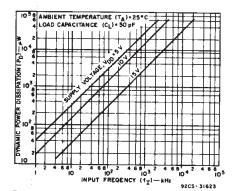


Fig. 12 — Typical power dissipation as a function of input frequency,

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DYNAMIC CHARACTERISTICS at TA=25°C, CL=50 pF, Input t_r,t_f=20 ns, R_L=200 k Ω unless otherwise specified

	TEST CONDITIONS		LIM		
CHARACTERISTIC		V _{DD}	All Packa	UNITS	
		V	Тур.	Max.	·
Propagation Delay: tpHL,tpLH		5	300	600	
Inputs to Output and		10	150	300	
Ka to Output		15	120	240	
Kb to Output		5	225	450	
		10	85	170	
		15.	55	110	
Kc to Output		5	140	280	
		10	50	100	
		15	40	80	
Expand Input to Output		5	190	380	ns
	ŀ	10	90	180	
	· ·	15	65	130	
3-State Propagation Delay:	B 410	5	80	160	
Kd to Output tpHZ,tpLZ	R _L =1 kΩ	10	35	70	-
tPZH,tPZL	See Fig.21	15	25	50	
Transition Time: tTHL,tTLH		5	100	200	
11190 1100	!	10	50	100	
		15	40	80	
Input Capacitance: C ₁	Any Input		5	7	pF
3-State Output Capacitance			5	10	pr

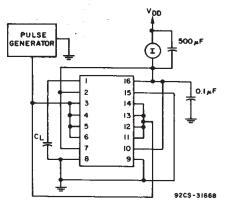


Fig. 13 – Dynamic power dissipation test circuit.

FUNCTION TRUTH TABLE

OUTPUT	BOOLEAN EXPRESSION	Ka	Кь	Kc	UNUSED	
NOR	J=A+B+C+D+E+F+G+H	0	0	0	V _{SS}	
OR	J=A+B+C+D+E+F+G+H	o	ō	1	V _{SS}	
OR/AND	J=(A+B+C+D)+(E+F+G+H)	0	1	0	V _{SS}	
OR/NAND	J=(A+B+C+D)·(E+F+G+H)	0	1	1	V _{SS}	
AND	J=ABCDEFGH	1	0	0	V _{DD}	
NAND	J=ABCDEFGH	1	0	1	V _{DD}	
AND/NOR	J=ABCD+EFGH	1	1	0	V _{DD}	
AND/OR	J=ABCD+EFGH	1	1	1	VDD	
K _d =1 Normal Inverter Action						
K _d =0 High Impedance Output						

EXPAND Input=0

* See Figs. 1,2,3,4, and 5.

TEST CIRCUITS - STATIC MEASUREMENTS

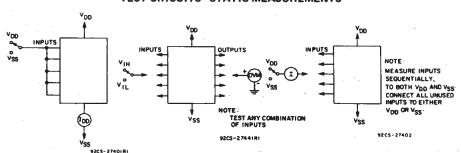


Fig. 14 — Quiescent device current test circuit.

Fig. 15 — Input voltage test circuit.

Fig. 16 - Input current test circuit.

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TEST CIRCUITS - DYNAMIC MEASUREMENTS

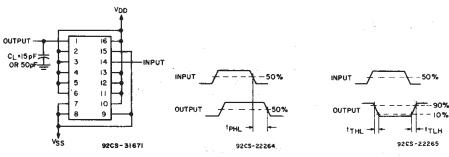


Fig. 17 — Test circuit for t_{PHL}, t_{THL}, and t_{TLH} (AND) measurements.

Fig. 18 — Waveforms for t_{PHL} and t_{PHL} (AND).

Fig. 19 — Waveforms for t_{THL} and t_{TLH} (AND).

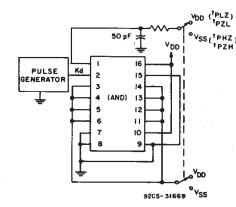


Fig. 20 — Test circuit for t_{PZL} , t_{PZH} , t_{PLZ} , and t_{PHZ} (AND).

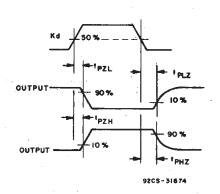
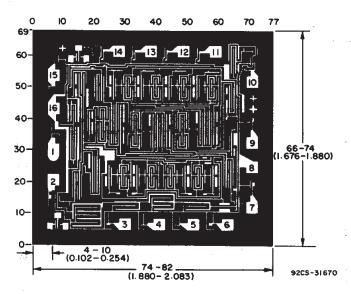


Fig. 21 – Waveforms for t_{PZL} , t_{PZH} , t_{PLZ} , and t_{PHZ} (AND).



Dimensions and pad layout for CD4048BH.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch) .

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